DECLARATIO	AN P	OWER OF	ATTORNEY	FOR	PATENTAPPLICATION
					OCKET NO. TS01-1132

As a below named Inventor, I nereby declare that:

My residence, post office address and citizenship are as stated below next to my name;

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled Complementary Metal Oxide Semiconductor Transistor Technology Using Selective Epitaxy Of A Strained Silicon Germanium Layer

the specification of which (check one)		
X is attached hereto.		
was filed on		·
Application Serial No.		
and was amended on(if ap		
t hereby state that I have reviewed and ur amended by any amendment referred to a	iderstand the contents of the a	bove Identified specification including the claims, as
I acknowledge the duty to disclose inform Title 37, Code of Federal Regulations, §1	nation which is material to the .56(a).	examination of this application in accordance with
I hereby claim foreign priority benefits un inventor's certificate listed below and hav having a filing date before that of the app Prior Foreign Application(s)	ve also identified below any fo	ode §119 of any foreign application(s) for patent or
		Priority Claimed:
(Number)	(Country)	(Day/Month/Year Filed)
(Number)	(Country)	(Day/Month/Year Filed)
manner provided by the first paragraph of information as defined in Title 37, Code capplication and the national or PCT international o	Trile 35. United States Code of Federal Regulations, §1.56( pational filing date of this app	ny United States application(s) listed below and, insofa closed in the prior United States application in the \$112, I acknowledge the duty to disclose material a) which occurred between the filing date of the prior dication:
(Application Serial No.)	(Filing Date) (Status)	(patented, pending, abandoned)
belief are believed to be true; and further	that these statements were ma	are true and that all statements made on information and de with the knowledge that willful false statements and r Section 1001 of Title 18 of the United States Code application or any patent issued thereon.
POWER OF ATTORNEY: As a named in application and transact all business in the	nventor, I hereby appoint the separate of the	following attorney(s) and/or agent(s) to prosecute this connected therewith. (list name & registration no.)
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YEE-CHIA YEO		November 27, 2001.
Full name of sole or first inventor  Yeachia Yeo.		Date
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